

2SAR513R

PNP -1.0A -50V Middle Power Transistor

| Parameter        | Value |
|------------------|-------|
| V <sub>CEO</sub> | –50V  |
| Ι <sub>C</sub>   | -1.0A |

### Features

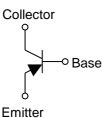
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR513R
- 3) Low V<sub>CE(sat)</sub>

 $V_{CE(sat)} = -0.4V(Max.)$ 

 $(I_C/I_B = -500 \text{mA}/ -25 \text{mA})$ 

4) Lead Free/RoHS Compliant.

### Inner circuit



# Applications

Outline

Base

Emitter

2SAR513R

(SC-96)

Collector

TSMT3

Motor driver , LED driver Power supply

| Packaging specifications |         |                         |                |                   |                    |                                 |         |
|--------------------------|---------|-------------------------|----------------|-------------------|--------------------|---------------------------------|---------|
| Part No.                 | Package | Package<br>size<br>(mm) | Taping<br>code | Reel size<br>(mm) | Tape width<br>(mm) | Basic<br>ordering<br>unit (pcs) | Marking |
| 2SAR513R                 | TSMT3   | 2928                    | TL             | 180               | 8                  | 3,000                           | MC      |

### ●Absolute maximum ratings (Ta = 25°C)

| Parameter                    |        | Symbol                        | Values      | Unit |
|------------------------------|--------|-------------------------------|-------------|------|
| Collector-base voltage       |        | V <sub>CBO</sub>              | -50         | V    |
| Collector-emitter voltage    |        | V <sub>CEO</sub>              | -50         | V    |
| Emitter-base voltage         |        | V <sub>EBO</sub>              | -6          | V    |
| Collector current            | DC     | Ι <sub>C</sub>                | -1.0        | А    |
|                              | Pulsed | I <sub>CP</sub> <sup>*1</sup> | -2.0        | А    |
| Power dissipation            |        | P <sub>D</sub> <sup>*2</sup>  | 0.5         | W    |
|                              |        | P <sub>D</sub> <sup>*3</sup>  | 1.0         | W    |
| Junction temperature         |        | Tj                            | 150         | °C   |
| Range of storage temperature |        | T <sub>stg</sub>              | -55 to +150 | °C   |

\*1 Pw=10ms , single pulse

\*2 Each terminal mounted on a reference land

\*3 Mounted on a ceramic board (40×40×0.7mm)

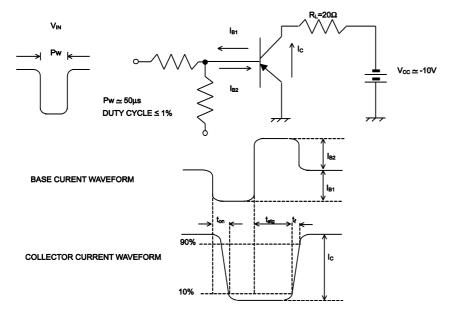
#### •Electrical characteristics(Ta = 25°C)

| Parameter                              | Symbol               | Conditions  | Min. | Тур.  | Max.  | Unit |
|--|----------------------|---|------|-------|-------|------|
| Collector-emitter<br>breakdown voltage | $BV_{CEO}$           | $I_{C} = -1mA$  | -50  | -     | -     | V    |
| Collector-base<br>breakdown voltage    | BV <sub>CBO</sub>    | $I_{C} = -100 \mu A$                                    | -50  | -     | -     | V    |
| Emitter-base<br>breakdown voltage      | $BV_{EBO}$           | I <sub>E</sub> = -100μA                                 | -6   | -     | -     | V    |
| Collector cut-off current              | I <sub>CBO</sub>     | $V_{CB} = -50V$   | -    | -     | -1    | μA   |
| Emitter cut-off current                | I <sub>EBO</sub>     | V <sub>EB</sub> = -4V                                   | -    | -     | -1    | μA   |
| Collector-emitter saturation voltage   | V <sub>CE(sat)</sub> | $I_{C} = -500 \text{mA}, I_{B} = -25 \text{mA}$         | -    | -0.20 | -0.40 | V    |
| DC current gain                        | h <sub>FE</sub>      | $V_{CE} = -2V, I_C = -50 \text{mA}$                     | 180  | -     | 450   | -    |
| Transition frequency                   | $f_{T}^{*1}$         | $V_{CE} = -10V, I_{E} = -200mA$<br>f=100MH <sub>Z</sub> | -    | 400   | -     | MHz  |
| Output capacitance                     | C <sub>ob</sub>      | $V_{CB} = -10V, I_E = 0A,$<br>f = 1MHz                  | -    | 12    | -     | pF   |
| Turn-on time                           | t <sub>on</sub> *2   | I <sub>C</sub> = -0.5A                                  | -    | 40    | -     | ns   |
| Storage time                           | t <sub>stg</sub> *2  | I <sub>B1</sub> = –50mA<br>I <sub>B2</sub> =50mA        | -    | 250   | -     | ns   |
| Fall time                              | t <sub>f</sub> *2    | V <sub>CC</sub> ≃ −10V                                  | -    | 35    | -     | ns   |

\*1 Pulsed

\*2 See switching time test circuit

## •Switching time test circuit



## •Electrical characteristic curves(Ta = 25°C)

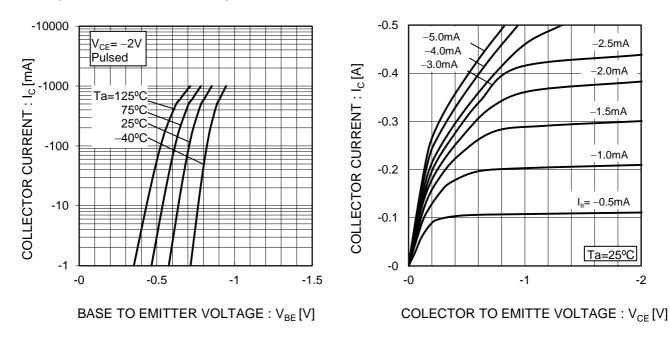
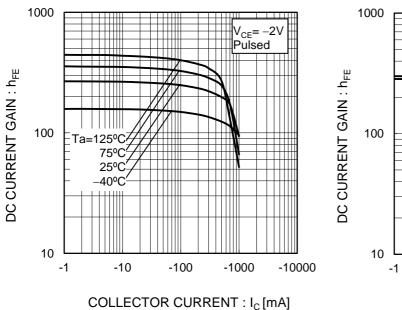
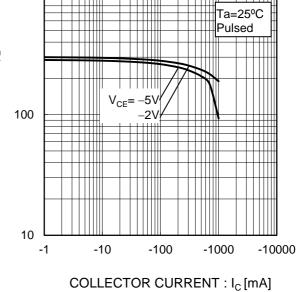


Fig.1 Ground Emitter Propagation Characteristics Fig.2 Typical Output Characteristics

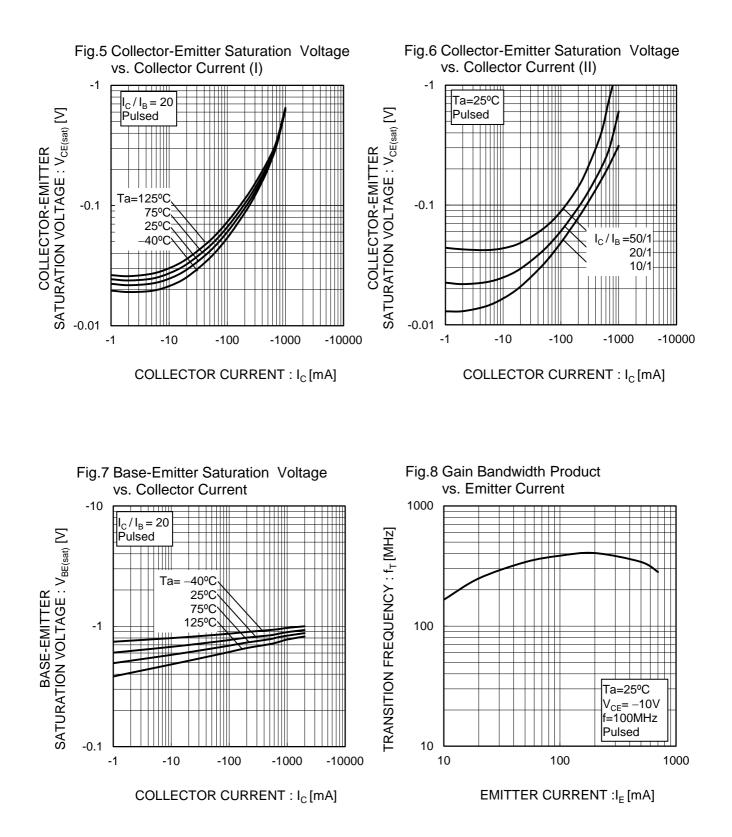
Fig.3 DC Current Gain vs. Collector Current(I)

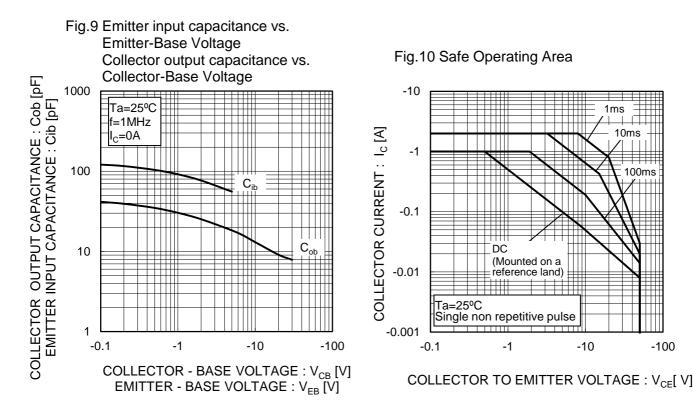
Fig.4 DC current gain vs. output current (II)





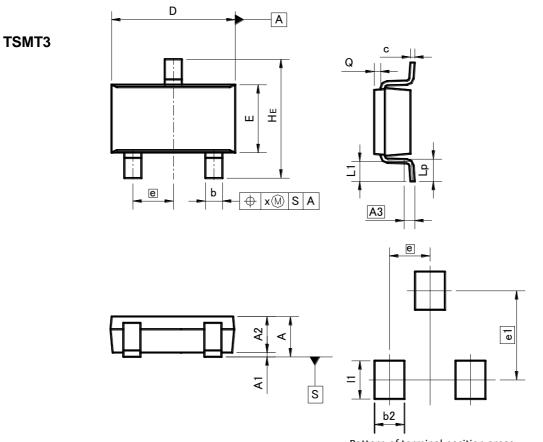
#### •Electrical characteristic curves(Ta = 25°C)





#### •Electrical characteristic curves(Ta = 25°C)

#### •Dimensions (Unit : mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| DIM | MILIM | ETERS | INCHES |       |  |
|-----|-------|-------|--------|-------|--|
| DIM | MIN   | MAX   | MIN    | MAX   |  |
| A   | -     | 1.00  | -      | 0.039 |  |
| A1  | 0.00  | 0.10  | 0.000  | 0.004 |  |
| A2  | 0.75  | 0.95  | 0.030  | 0.037 |  |
| A3  | 0.:   | 25    | 0.0    | 10    |  |
| b   | 0.35  | 0.50  | 0.014  | 0.020 |  |
| с   | 0.10  | 0.26  | 0.004  | 0.010 |  |
| D   | 2.80  | 3.00  | 0.110  | 0.118 |  |
| E   | 1.50  | 1.80  | 0.059  | 0.071 |  |
| е   | 0.95  |       | 0.0    | 37    |  |
| HE  | 2.60  | 3.00  | 0.102  | 0.118 |  |
| L1  | 0.30  | 0.60  | 0.012  | 0.024 |  |
| Lp  | 0.40  | 0.70  | 0.016  | 0.028 |  |
| Q   | 0.05  | 0.25  | 0.002  | 0.010 |  |
| х   | _     | 0.20  | _      | 0.008 |  |

| DIM | MILIMETERS |      | INCHES |       |  |
|-----|------------|------|--------|-------|--|
| DIM | MIN        | MAX  | MIN    | MAX   |  |
| b2  |            | 0.70 | -      | 0.028 |  |
| e1  | 2.10       |      | 0.0    | 83    |  |
| 1   | -          | 0.90 | -      | 0.035 |  |

Dimension in mm / inches

|     | Notes  |
|-----|--|
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